

**SMALL SIGNAL SCHOTTKY DIODE**
**DESCRIPTION**

General purpose metal to silicon diode featuring very low turn-on voltage and fast switching.

This device has integrated protection against excessive voltage such as electrostatic discharges.


**ABSOLUTE RATINGS** (limiting values)

Symbol	Parameter		Value	Unit
$V_{RRM}$	Repetitive Peak Reverse Voltage		100	V
$I_F$	Forward Continuous Current*	$T_a = 25^\circ\text{C}$	100	mA
$I_{FRM}$	Repetitive Peak Forward Current*	$t_p \leq 1\text{s}$ $\delta \leq 0.5$	350	mA
$I_{FSM}$	Surge non Repetitive Forward Current*	$t_p = 10\text{ms}$	750	mA
$P_{101}$	Power Dissipation*	$T_a = 95^\circ\text{C}$	100	mW
$T_{stg}$ $T_j$	Storage and Junction Temperature Range		- 65 to 150 - 65 to 125	$^\circ\text{C}$ $^\circ\text{C}$
$T_L$	Maximum Lead Temperature for Soldering during 10s at 4mm from Case		230	$^\circ\text{C}$

**THERMAL RESISTANCE**

Symbol	Parameter	Value	Unit
$R_{th(j-a)}$	Junction-ambient*	300	$^\circ\text{C/W}$

**ELECTRICAL CHARACTERISTICS**
**STATIC CHARACTERISTICS**

Symbol	Test Conditions		Min.	Typ.	Max.	Unit
$V_{(BR)}$	$T_j = 25^\circ\text{C}$	$I_R = 100\mu\text{A}$	100			V
$V_F^{**}$	$T_j = 25^\circ\text{C}$	$I_F = 1\text{mA}$		0.4	0.45	V
	$T_j = 25^\circ\text{C}$	$I_F = 200\text{mA}$			1	
$I_R^{**}$	$T_j = 25^\circ\text{C}$	$V_R = 50\text{V}$			0.1	$\mu\text{A}$
	$T_j = 100^\circ\text{C}$				20	

**DYNAMIC CHARACTERISTICS**

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
C	$T_j = 25^\circ\text{C}$	$V_R = 1\text{V}$	$f = 1\text{MHz}$		2		pF

\* On infinite heatsink with 4mm lead length

\*\* Pulse test :  $t_p \leq 300\mu\text{s}$   $\delta < 2\%$ .

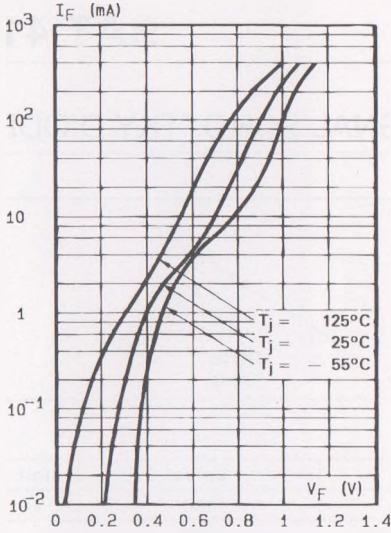


Fig.1 Forward current versus forward voltage at different temperatures (typical values).

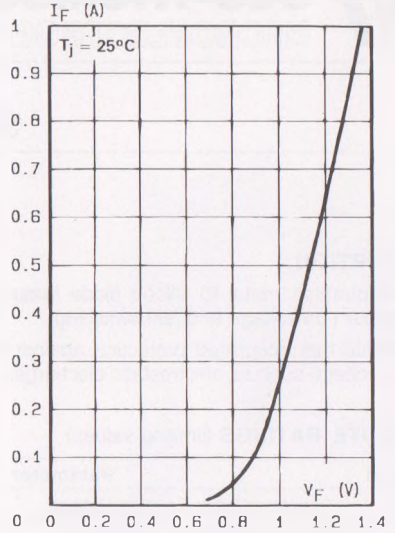


Fig.2 Forward current versus forward voltage (typical values).

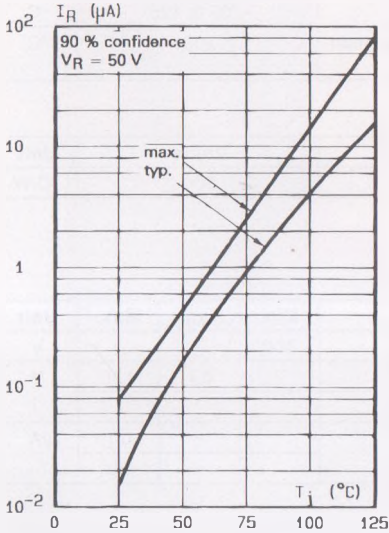


Fig.3 - Reverse current versus junction temperature.

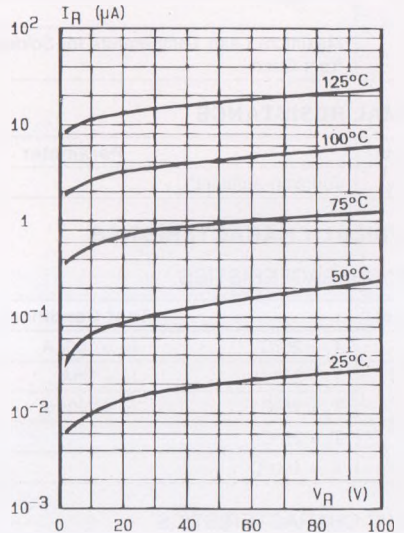


Fig.4 - Reverse current versus continuous reverse voltage (typical values).

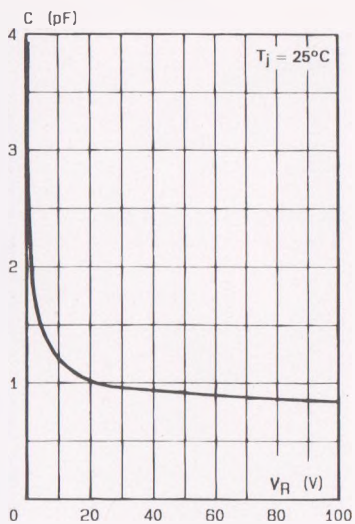


Fig.5 - Capacitance  $C$  versus reverse applied voltage  $V_R$  (typical values).